NSN 5961-01-281-5574



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-281-5574 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** Between 0.475 inches and 0.525 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **Function For Which Designed:** Switching **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -12.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and -12.0 breakdown voltage, collector-to-base, emitter open and -4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 80.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

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Demilitarization: